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325 Twelfth p-MOS logic transistor
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- 326 First n-MOS logic transistor
- 327 Second n-MOS logic transistor
- 328 Third n-MOS logic transistor
- 5 329 Fourth n-MOS logic transistor
  - 330 Fifth n-MOS logic transistor
  - 331 Sixth n-MOS logic transistor
  - 332 Seventh n-MOS logic transistor
  - 333 Eighth n-MOS logic transistor
- 10 334 Ninth n-MOS logic transistor
  - 335 Tenth n-MOS logic transistor
  - 336 Eleventh n-MOS logic transistor
  - 337 Twelfth n-MOS logic transistor
  - 338 First logic function input
- 15 339 Second logic function input
  - 340 Third logic function input
  - 341 Fourth logic function input
  - 342 Third inverter circuit
  - 343 Third n-MOS inverter transistor
- 20 344 Third p-MOS inverter transistor
  - 350 First data signal input
  - 351 Second data signal input
  - 352 Node
  - 400 Logic basic cell array
- 25 401a Third p-MOS logic transistor
  - 401b Fourth p-MOS logic transistor
  - 402a Third n-MOS logic transistor
  - 402b Fourth n-MOS logic transistor
  - 403 Node
- 30 404 Global node
  - 410 p-MOS subcircuit
  - 411 n-MOS subcircuit
  - 412 First p-MOS logic basic cell
  - 413 Second p-MOS logic basic cell
- 35 414 First n-MOS logic basic cell

- 415 Second n-MOS logic basic cell
- 500 Logic basic cell array
- 501 Evaluation field effect transistor
- 502 Precharge field effect transistor
- 5 503 Evaluation input
  - 504 Precharge input
  - 505 Global output
  - 600 p-MOS partial path
  - 601 First metallization plane
- 10 602 Second metallization plane
  - 603 Via
  - 604 Power via
  - 610 n-MOS partial path